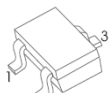


APPLICATION

- Load Switch for Portable Devices
- DC/DC Converter

FEATURE

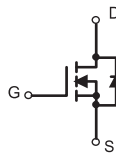
- High density cell design for low $R_{DS(on)}$
- Voltage controlled small signal switch
- Rugged and reliable
- High saturation current capability



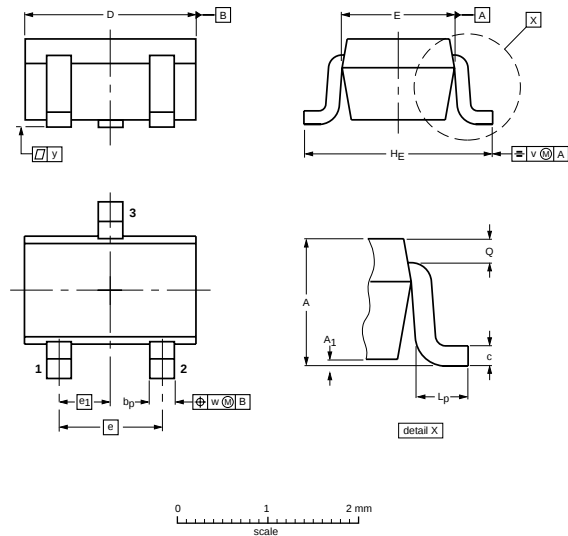
SOT-323

1. BASE
2. EMITTER
3. COLLECTOR

Equivalent Circuit



SOT-323



DIMENSIONS (mm are the original dimensions)

UNIT	A	A ₁ max	b _p	c	D	E	e	e ₁	H _E	L _p	Q	v	w
mm	1.1 0.8	0.1	0.4 0.3	0.25 0.10	2.2 1.8	1.35 1.15	1.3	0.65	2.2 2.0	0.45 0.15	0.23 0.13	0.2	0.2

MAXIMUM RATINGS (T_a=25°C unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V _{DS}	60	V
Gate-Source Voltage	V _{GS}	± 20	V
Continuous Drain Current	I _D	0.3	A
Power Dissipation	P _D	0.200	W
Thermal Resistance from Junction to Ambient	R _{θJA}	625	°C/W
Junction Temperature	T _J	150	°C
Storage Temperature	T _{stg}	-50 ~ +150	

2N7002W

$T_a=25\text{ }^{\circ}\text{C}$ unless otherwise specified

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS}=0\text{ V}$, $I_D=250\text{ }\mu\text{A}$	60			V
Gate-Threshold Voltage	$V_{(GS)th}$	$V_{DS}=V_{GS}$, $I_D=250\text{ }\mu\text{A}$	1	1.6	2.5	
Gate-body Leakage	I_{GSS}	$V_{DS}=0\text{ V}$, $V_{GS}=\pm 20\text{ V}$			± 80	nA
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=60\text{ V}$, $V_{GS}=0\text{ V}$			80	nA
On-state Drain Current	$I_{D(on)}$	$V_{GS}=10\text{ V}$, $V_{DS}=7\text{ V}$	500			mA
Drain-Source On-Resistance	$R_{DS(on)}$	$V_{GS}=10\text{ V}$, $I_D=500\text{ mA}$		0.9	5	Ω
		$V_{GS}=5\text{ V}$, $I_D=50\text{ mA}$		1.1	7	
Forward Trans conductance	g_{fs}	$V_{DS}=10\text{ V}$, $I_D=200\text{ mA}$	80			ms
Drain-source on-voltage	$V_{DS(on)}$	$V_{GS}=10\text{ V}$, $I_D=500\text{ mA}$			3.75	V
		$V_{GS}=5\text{ V}$, $I_D=50\text{ mA}$			0.375	V
Diode Forward Voltage	V_{SD}	$I_S=115\text{ mA}$, $V_{GS}=0\text{ V}$	0.55		1.2	V
Input Capacitance *	C_{iss}	$V_{DS}=25\text{ V}$, $V_{GS}=0\text{ V}$, $f=1\text{ MHz}$			50	pF
Output Capacitance*	C_{oss}				25	
Reverse Transfer Capacitance*	C_{rss}				5	

SWITCHING TIME

Turn-on Time*	$t_{d(on)}$	$V_{DD}=25\text{ V}$, $R_L=50\Omega$, $I_D=500\text{ mA}$, $V_{GEN}=10\text{ V}$ $R_G=25\Omega$			20	ns
Turn-off Time*	$t_{d(off)}$				40	

*These parameters have no way to verify.

RATING AND CHARACTERISTIC CURVES (2N7002W)

